

H11L1, H11L2, H11L3, H11L4



ISOCOM
COMPONENTS

**MICROPROCESSOR COMPATIBLE
SCHMITT TRIGGER OPTICALLY
COUPLED ISOLATOR**



DESCRIPTION

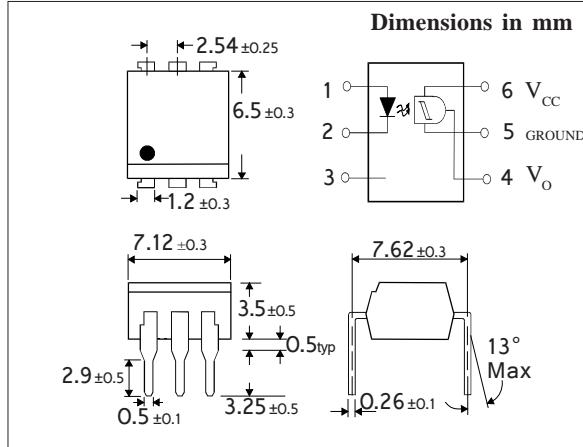
The H11L1, 2, 3, 4 series are optically coupled isolators consisting of a Gallium Arsenide infrared emitting diode and a Microprocessor Compatible Schmitt trigger output mounted in a standard 6 pin dual in line package.

FEATURES

- Options :-
 - 10mm lead spread - add G after part no.
 - Surface mount - add SM after part no.
 - Tape&reel - add SMT&R after part no.
- High data rate, 1MHz typical (NRZ)
- Microprocessor compatible drive
- Logic compatible output sinks 16 milliamperes at 0.4 volts maximum
- High Isolation Voltage (5kV_{RMS}, 7kV_{PK})
- High common mode rejection ratio
- Fast switching : t_{rise}, t_{fall} = 100nS typical
- Wide supply voltage capability, compatible with all popular logic systems
- Guaranteed On / Off threshold hysteresis

APPLICATIONS

- Logic to logic isolator
- Line receiver-eliminates noise and transient problems
- Programmable current level sensor
- AC to TTL conversion - square wave shaping
- Digital programming of power supplies
- Interfaces computers with peripherals



**ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)**

Storage Temperature	-40°C to +125°C
Operating Temperature	-25°C to +85°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

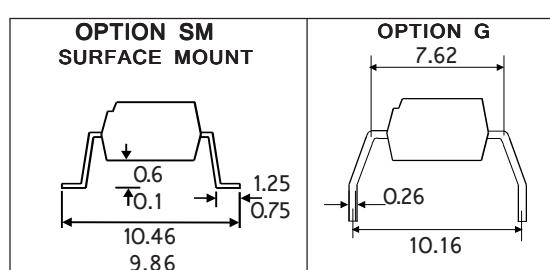
Forward Current, I _F	50mA
Peak forward current (Pulse width ≤ 100uS, Duty ratio=0.001)	1A
Reverse Voltage, V _R	6V
Power Dissipation (derate linearly 1.41mW / °C above 25°C)	70mW

OUTPUT DETECTOR

Output Voltage, V _{CC}	16V
Supply Voltage, V _{OH}	16V
Output current, I _{OL}	50mA
Power Dissipation (derate linearly 2mW / °C above 25°C)	150mW

POWER DISSIPATION

Total Power Dissipation (derate linearly 2.94mW/ °C above 25°C)	170mW
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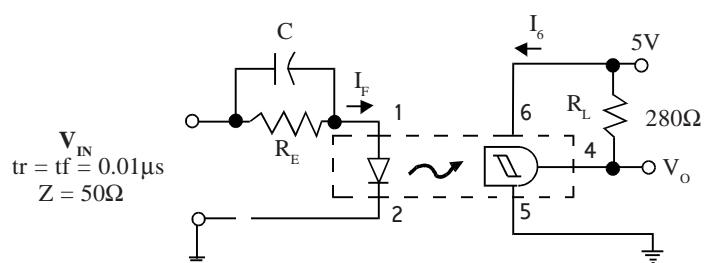
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F) Forward Voltage (V_F) Reverse Current (I_R) Capacitance (C_J)	0.75		10 100	V μA pF	$I_F = 0.3\text{mA}$ $I_F = 10\text{mA}$ $V_R = 3\text{V}$ $V = 0, f = 1\text{MHz}$
Output	Operating Voltage Range (V_{CC}) Supply Current I_6 (off) Output Current High (I_{OH})	3	1.6	15 5 100	V mA μA	$I_F = 0\text{mA}, V_{CC} = 5\text{V}$ $I_F = 0\text{mA}, V_{CC} = V_O = 15\text{V}$
Coupled	Supply Current I_6 (on) Output Voltage, Low (V_{OL}) Turn-on Threshold Current I_F (on) H11L1 H11L2 H11L3 H11L4 Turn-off Threshold Current I_F (off) Hysteresis Ratio I_F (off) / I_F (on) Input to Output Isolation Voltage V_{ISO} High to Low Propagation time Fall Time Low to High Propagation time Rise Time		1.6	5 0.4 1.6 10 5 2 0.3 0.5 5000 7000	mA V mA mA mA mA mA V_{RMS} V_{PK} μs μs μs μs	$I_F = 10\text{mA}, V_{CC} = 5\text{V}$ $R_L = 270\Omega, V_{CC} = 5\text{V}$ See note 1 See note 1 $R_E = 280\Omega$ $V_{CC} = 5\text{V}$ $I_F = 4\text{mA}$

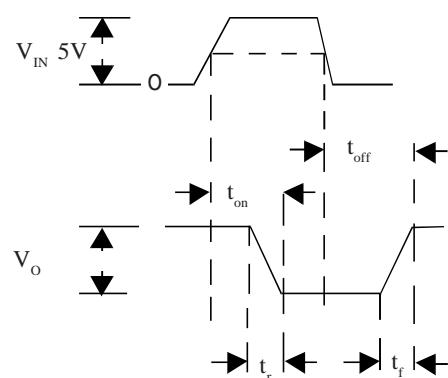
Note 1 Measured with input leads shorted together and output leads shorted together for 1 minute

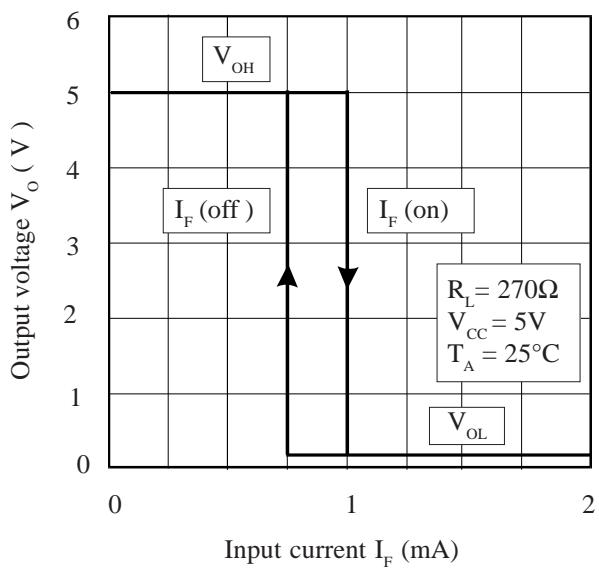
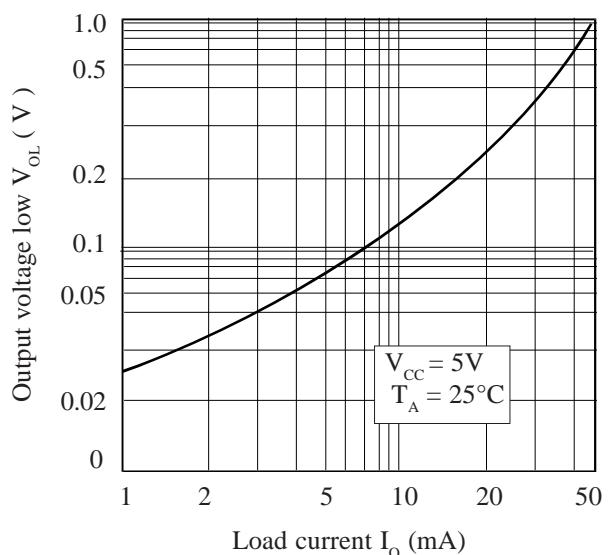
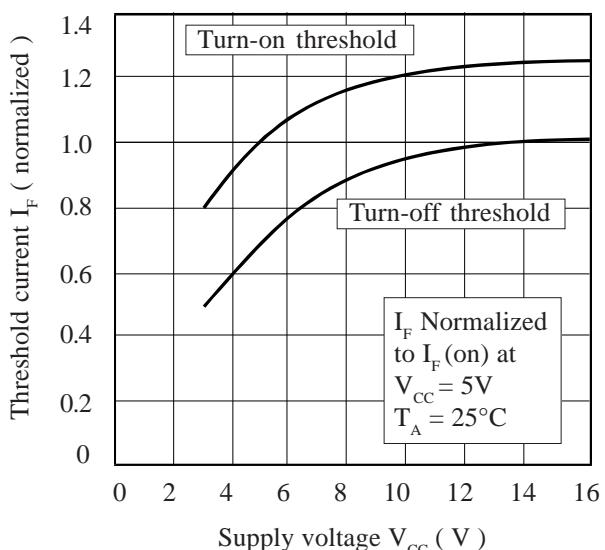
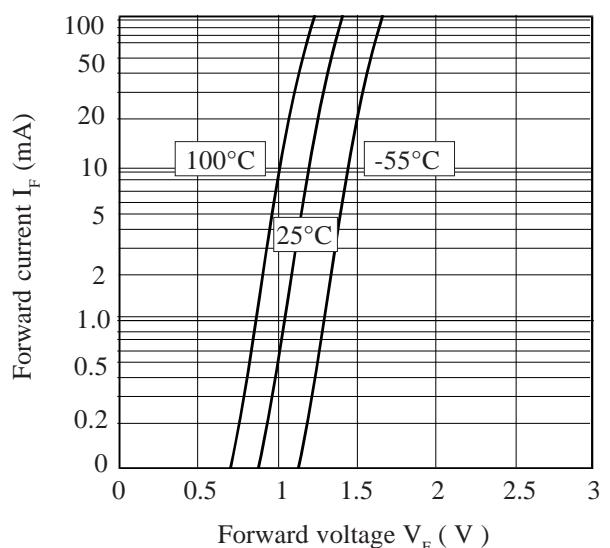
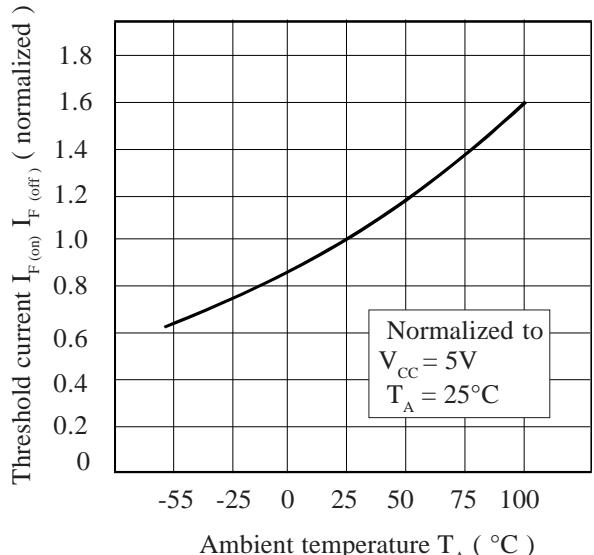
Note 2 Special Selections are available on request. Please consult the factory.

SWITCHING CHARACTERISTICS



SWITCHING TEST CIRCUIT



Transfer Characteristics**On Voltage vs. Load Current****Threshold Current vs. Supply Voltage****Forward Voltage vs. Forward Current****Threshold Current vs. Ambient Temperature****Supply Current vs. Supply Voltage**